TOSHIBA Field Effect Transistor Silicon P Channel MOS Type (U-MOSVI)

TPC8124

Lithium Ion Battery Applications Power Management Switch Applications

Unit: mm

- Small footprint due to small and thin package
- Low drain-source ON-resistance: $RDS(ON) = 6.1 \text{ m}\Omega \text{ (typ.)}$
- Low leakage current: $I_{DSS} = -10 \,\mu A \,(max) \,(V_{DS} = -40 \,V)$
- Enhancement mode: V_{th} = -0.8 to -2.0 V (V_{DS} = -10 V, I_{D} = -0.5mA)

Absolute Maximum Ratings (Ta = 25°C)

Characteri	stics	Symbol	Rating	Unit	
Drain-source voltage		V_{DSS}	-40	V	
Drain-gate voltage (Ro	_{SS} = 20 kΩ)	V_{DGR}	-40	V	
Gate-source voltage		V _{GSS}	-25/+20	V	
Drain current	DC (Note 1)	I _D	-12	Α	
Diain current	Pulse (Note 1)	I _{DP}	-48	^	
Drain power dissipatio	n (t = 10 s) (Note 2a)	P _D	1.9	W	
Drain power dissipatio	n (t = 10 s) (Note 2b)	P_{D}	1.0	W	
Single pulse avalanche	e energy (Note 3)	E _{AS}	134	mJ	
Avalanche current	(Note 1)	I _{AR}	-12	Α	
Channel temperature		T _{ch}	150	°C	
Storage temperature r	ange	T _{stg}	-55 to 150	°C	

Note 1, Note 2, Note 3: See the next page.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum

0.595TVP 1.27

5.5MAX

5.0±0.2

1, 2, 3 SOURCE
4 GATE
5, 6, 7, 8 DRAIN

JEDEC

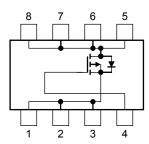
JEITA

TOSHIBA

2-6J1B

Weight: 0.080 g (typ.)

Circuit Configuration



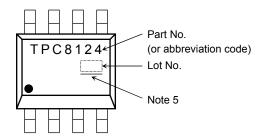
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

This transistor is an electrostatic-sensitive device. Handle with care.

Thermal Characteristics

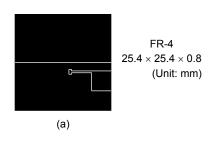
Characteristics	Symbol	Max	Unit
Thermal resistance, channel to ambient (t = 10 s) (Note 2a)	R _{th (ch-a)}	65.8	°C/W
Thermal resistance, channel to ambient (t = 10 s) (Note 2b)	R _{th (ch-a)}	125	°C/W

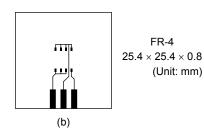
Marking (Note 4)



Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: (a)Device mounted on a glass-epoxy board (b) (b)Device mounted on a glass-epoxy board (b)

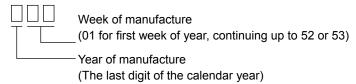




Note 3: $V_{DD} = -24$ V, $T_{ch} = 25$ °C (initial), L = 1.0 mH, $R_G = 25$ Ω , $I_{AR} = -12$ A

Note 4: • on lower left of the marking indicates Pin 1.

* Weekly code: (Three digits)



Note 5: A line under a Lot No. identifies the indication of product Labels.

Not underlined: [[Pb]]/INCLUDES > MCV

Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. The RoHS is the Directive 2002/95/EC of the European Parliament and of the Council of 27 January 2003 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

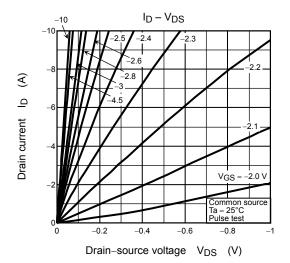
Electrical Characteristics (Ta = 25°C)

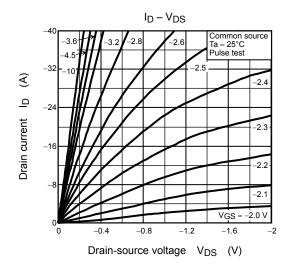
Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage curre	ent	I _{GSS}	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$	_	_	±100	nA
Drain cut-OFF cur	rent	I _{DSS}	$V_{DS} = -40 \text{ V}, V_{GS} = 0 \text{ V}$	_	_	-10	μА
Drain-source breakdown voltage		V (BR) DSS	$I_D = -10 \text{ mA}, V_{GS} = 0 \text{ V}$	-40	_	_	
Drain-source brea	kdown voltage	V (BR) DSX	$I_D = -10 \text{ mA}, V_{GS} = 10 \text{ V}$ (Note 6)	-30 — — -0.8 — -2.0		_	
Gate threshold vol	tage	V _{th}	$V_{DS} = -10 \text{ V}, I_D = -0.5 \text{ mA}$	-0.8	_	-2.0	V
Drain aguras ON r	- cointana	D	$V_{GS} = -4.5 \text{ V}, I_D = -6 \text{ A}$	_	7.7	10	
		KDS (ON)	V _{GS} = -10 V, I _D = -6 A	_	6.1	8	mΩ
Input capacitance		C _{iss}	V _{DS} = -10 V, V _{GS} = 0 V, f = 1 MHz	_	4750	_	pF
Reverse transfer capacitance		C _{rss}		_	540	_	
Output capacitance		C _{oss}		_	620	_	
$R_{DS} \text{ (ON)} \qquad V_{GS} = -4.5 \text{ V}, \ I_D = -6 \text{ A} \\ V_{GS} = -10 \text{ V}, \ I_D = -6 \text{ A} \\ V_{GS} = -10 \text{ V}, \ I_D = -6 \text{ A} \\ V_{DS} = -10 \text{ V}, \ V_{DS} = -6 \text{ A} \\ V_{DS} = -10 \text{ V}, \ V_{DS} = 0 \text{ V} \\ V_{DS} = -10 \text{ V}, \ V_{DS} = 0 \text{ V} \\ V_{DS} = -10 \text{ V}, \ V_{DS} = 0 \text{ V} \\ V_{DS} = -10 \text{ V}, \ V_{DS} = 0 \text{ V} \\ V_{DS} = -10 \text{ V}, \ V_{DS} = 0 \text{ V} \\ V_{DS} = -10 \text{ V}, \ V_{DS} = 0 \text{ V} \\ V_{DS} = -10 \text{ V}, \ V_{DS} = 0 \text{ V} \\ V_{DS} = -10 \text{ V}, \ V_{DS} = 0 \text{ V} \\ V_{DS} = -10 \text{ V}, \ V_{DS} = 0 \text{ V} \\ V_{DS} = -10 \text{ V}, \ V_{DS} = 0 \text{ V} \\ V_{DS} = -10 \text{ V}, \ V_{DS} = 0 \text{ V} \\ V_{DS} = -10 \text{ V}, \ V_{DS} = 0 \text{ V} \\ V_{DS} = -10 \text{ V}, \ V_{DS} = 0 \text{ V} \\ V_{DS} = -10 \text{ V}, \ V_{DS} = 0 \text{ V} \\ V_{DS} = -10 \text{ V}, \ V_{DS} = 0 \text{ V} \\ V_{DS} = -10 \text{ V}, \ V_{DS} = 0 \text{ V} \\ V_{DS} = -10 \text{ V}, \ V_{DS} = 0 \text{ V} \\ V_{DS} = -10 \text{ V}, \ V_{DS} = 0 \text{ V} \\ V_{DS} = -10 \text{ V}, \ V_{DS} = 0 \text{ V} \\ V_{DS} = -10 \text{ V}, \ V_{DS} = 0 \text{ V} \\ V_{DS} = -10 \text{ V}, \ V_{DS} = 0 \text{ V} \\ V_{DS} = -10 \text{ V}, \ V_{DS} = 0 \text{ V} \\ V_{DS} = -10 \text{ V}, \ V_{DS} = 0 \text{ V} \\ V_{DS} = -10 \text{ V}, \ V_{DS} = 0 \text{ V} \\ V_{DS} = -10 \text{ V}, \ V_{DS} = 0 \text{ V} \\ V_{DS} = -10 \text{ V}, \ V_{DS} = 0 \text{ V} \\ V_{DS} = -10 \text{ V}, \ V_{DS} = 0 \text{ V} \\ V_{DS} = -10 \text{ V}, \ V_{DS} = 0 \text{ V} \\ V_{DS} = -10 \text{ V}, \ V_{DS} = 0 \text{ V} \\ V_{DS} = -10 \text{ V}, \ V_{DS} = 0 \text{ V} \\ V_{DS} = -10 \text{ V}, \ V_{DS} = 0 \text{ V} \\ V_{DS} = -10 \text{ V}, \ V_{DS} = 0 \text{ V} \\ V_{DS} = -10 \text{ V}, \ V_{DS} = 0 \text{ V} \\ V_{DS} = -10 \text{ V}, \ V_{DS} = 0 \text{ V} \\ V_{DS} = -10 \text{ V}, \ V_{DS} = 0 \text{ V} \\ V_{DS} = -10 \text{ V}, \ V_{DS} = 0 \text{ V} \\ V_{DS} = -10 \text{ V}, \ V_{DS} = 0 \text{ V} \\ V_{DS} = -10 \text{ V}, \ V_{DS} = 0 \text{ V} \\ V_{DS} = -10 \text{ V}, \ V_{DS} = 0 \text{ V} \\ V_{DS} = -10 \text{ V}, \ V_{DS} = 0 \text{ V} \\ V_{DS} = -10 \text{ V}, \ V_{DS} = 0 \text{ V} \\ V_{DS} = -10 \text{ V}, \ V_{DS} = 0 \text{ V} \\ V_{DS} = -10 \text{ V}, \ V_{DS} = 0 \text{ V} \\ V_{DS} = -10 \text{ V}, \ V_{DS} = 0 \text{ V} \\ V_{DS} = -10 \text{ V}, \ V_{DS} = 0 \text{ V} \\ V_{DS} = -10 \text{ V}, \$	Rise time	t _r	VGS 0 V 7	_	9	_	
		_	17	_			
	Fall time	t _f	4.7.5 3.4	_	110	_	- ns
	Turn-OFF time	t _{off}	$V_{DD} \approx -20 \text{ V}$ Duty \leq 1%, $t_W = 10 \mu\text{s}$	_	390	_	
Total gate charge (gate-source plus gate-drain)		Qg	$V_{DD} \approx -32 \text{ V}, V_{GS} = -10 \text{ V},$	_	104	_	nC
Gate-source charge 1		Q _{gs1}	$I_D = -12 \text{ A}$	_	10	_	
Gate-drain ("miller") charge		Q _{gd}		_	27	_	

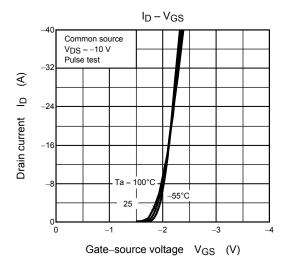
Source-Drain Ratings and Characteristics (Ta = 25°C)

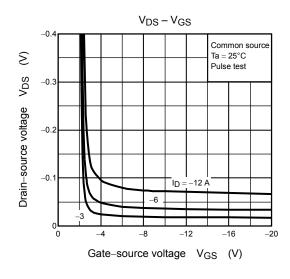
Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit	
Drain reverse current	Pulse	(Note 1)	I _{DRP}	_	_	_	-48	Α
Forward voltage (diode)		V _{DSF}	I _{DR} = -12 A, V _{GS} = 0 V	_	_	1.2	V	

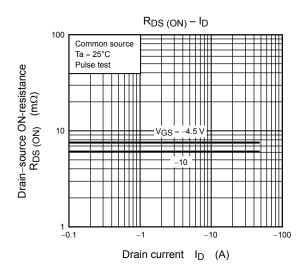
Note 6: VDSX mode (the application of a plus voltage between gate and source) may cause decrease in maximum rating of drain-source voltage.

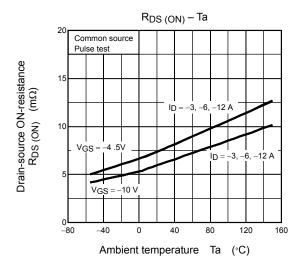


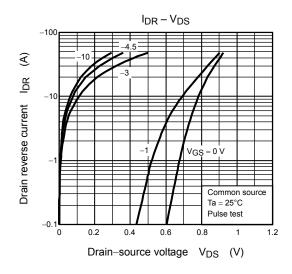


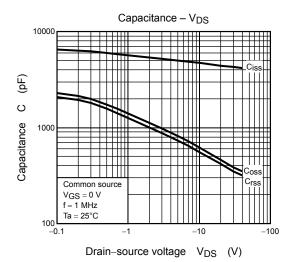


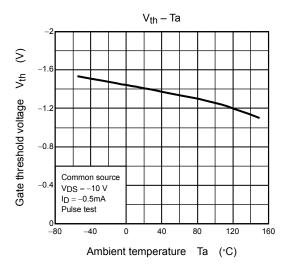


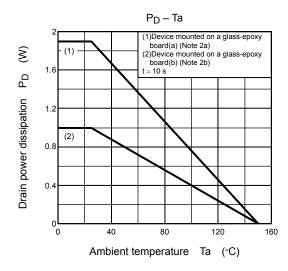


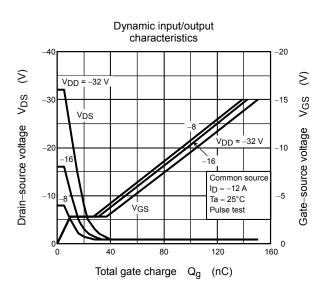


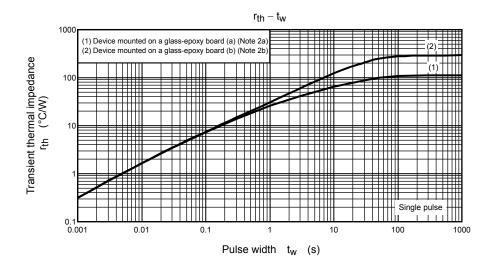


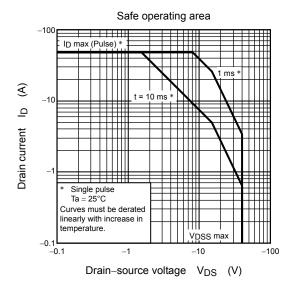












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